

Amendments to the Specification:

Please amend the specification by inserting the paragraph below, after the title on page 1.

Cross-Reference to Related Application

This application claims priority based on International Patent Application No. PCT/FR2003/05077, entitled "Method for Making a Detachable Semiconductor Substrate and For Obtaining a Semiconductor Element" by Chrystelle LAGAHE, Bernard ASPAR and Aurelie BEAUMONT, which claims priority of French Application No. 02/12443, filed on October 7, 2002 and French Application No. 03/50130, filed on April 25, 2003, which were not published in English.